NSN 5961-00-175-8225

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-175-8225 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 collector to base voltage, dc and 350.0 collector to emitter voltage, dc and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 1.00 amperes all primaries **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 88818-c532000523 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli